**Product data sheet** 

## 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT8002-3 (MLPAK33) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- Fully automotive qualified to AEC-Q101 at 175°C
- Side-wettable flanks for optical solder inspection

## 3. Applications

- LED Lighting
- Switching circuits
- DC-DC conversion

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	60	V
$V_{GS}$	gate-source voltage	DC; T <sub>j</sub> ≤ 175 °C		-20	-	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C	[1]	-	-	21	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C		-	-	27	W
Static charact	eristics						·
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 5.6 \text{ A}; T_j = 25 \text{ °C}$		-	23.7	29	mΩ
Dynamic characteristics							
$Q_{GD}$	gate-drain charge	$V_{DS} = 30 \text{ V}; I_D = 5.6 \text{ A}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}$		-	2.4	-	nC

<sup>[1] 21</sup> A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.



# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source	<u> </u>	
3	S	source		D ⊥
4	G	gate		
5	D	drain		
6	D	drain		mbb076 S
7	D	drain	8 7 6 5	
8	D	drain	MLPAK33 (SOT8002-3)	

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package					
	Name	Description	Version			
BUK9Q29-60E		plastic thermal enhanced surface mounted package with side-wettable flanks (SWF); mini leads; 8 terminals;pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-3			

## 7. Marking

Table 4. Marking codes

Type number	Marking code
BUK9Q29-60E	7AA

## 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{DS}$	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	60	V
$V_{GS}$	gate-source voltage	DC; T <sub>j</sub> ≤ 175 °C		-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C	[1]	-	21	А
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C		-	14.5	А
I <sub>DM</sub>	peak drain current	single pulse; $t_p \le 10 \mu s$ ; $T_{mb} = 25 °C$		-	84	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C		-	27	W
T <sub>j</sub>	junction temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-55	175	°C
Source-drain	diode					
Is	source current	T <sub>mb</sub> = 25 °C	[1]	-	21	А
I <sub>SM</sub>	peak source current	single pulse; $t_p \le 10 \mu s$ ; $T_{mb} = 25  ^{\circ}C$	[1]	-	84	Α

Symbol	Parameter	Conditions		Min	Max	Unit
Avalanche ruggedness						
E <sub>DS(AL)S</sub>		$V_{sup}$ < 60 V; $V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; $R_{GS}$ = 50 $\Omega$ ; $I_{D}$ = 15.8 A; unclamped	[2] [3]	-	25	mJ

- [1] 21 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.
- [2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [3] Refer to application note AN10273 for further information.

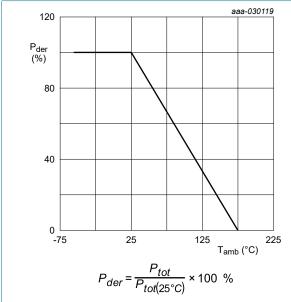


Fig. 1. Normalized total power dissipation as a function of ambient temperature

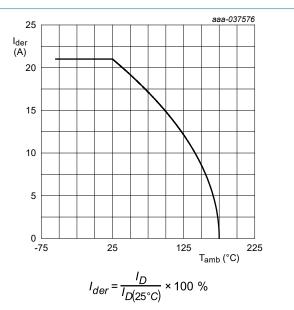


Fig. 2. Continuous drain current as a function of ambient temperature

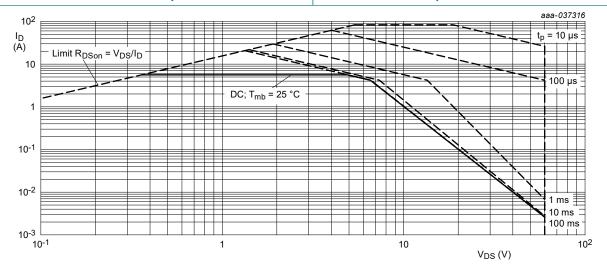
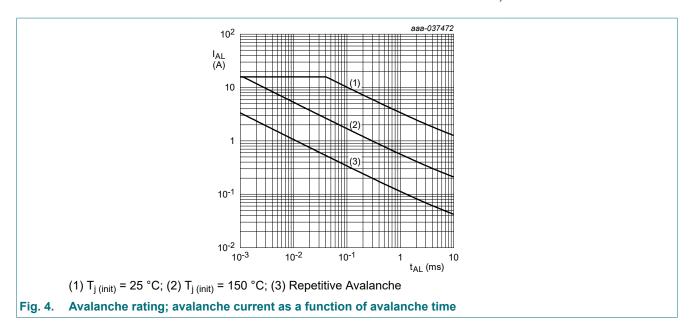


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

### **60 V, N-channel Trench MOSFET**



### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
uig-iiib)	thermal resistance from junction to mounting base		-	3.5	5.5	K/W	

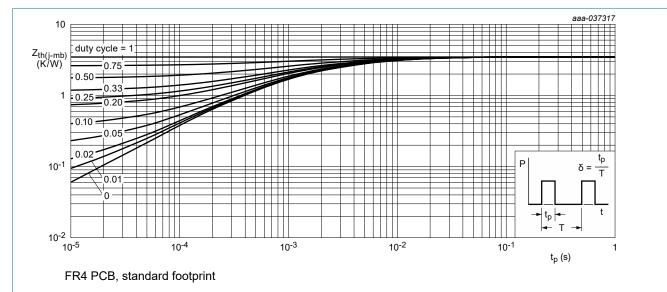


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

# 10. Characteristics

### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	60	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.3	1.7	2.1	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-	1	μΑ
		V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 125 °C	-	-	20	μΑ
		V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C	-	-	400	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	0.1	μΑ
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-0.1	μΑ
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = 10 V; $I_D$ = 5.6 A; $T_j$ = 25 °C	-	23.7	29	mΩ
	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.6 A; T <sub>j</sub> = 105 °C	-	39	51.4	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.6 A; T <sub>j</sub> = 125 °C	-	42.4	55.9	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5.6 A; T <sub>j</sub> = 175 °C	-	52	64	mΩ
		$V_{GS} = 4.5 \text{ V}; I_D = 4.9 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	28	38	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.9 A; T <sub>j</sub> = 105 °C	-	45.3	63.9	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.9 A; T <sub>j</sub> = 125 °C	-	49.2	69.5	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.9 A; T <sub>j</sub> = 175 °C	-	60.9	83.6	mΩ
9 <sub>fs</sub>	forward transconductance	$V_{DS} = 5 \text{ V}; I_D = 5.6 \text{ A}$	-	18.6	-	S
$R_G$	gate resistance	f = 1 MHz	-	2	-	Ω
Dynamic ch	naracteristics					
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = 30 V; I <sub>D</sub> = 5.6 A; V <sub>GS</sub> = 10 V;	-	12	18	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1.6	-	nC
$Q_{GD}$	gate-drain charge		-	2.4	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 30 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	660	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	67	-	pF
C <sub>rss</sub>	reverse transfer capacitance	_	-	40	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 30 V; I <sub>D</sub> = 5.6 A; V <sub>GS</sub> = 10 V;	-	3	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	4	-	ns
t <sub>d(off)</sub>	turn-off delay time	1	-	13	-	ns
t <sub>f</sub>	fall time	1	-	5	-	ns
Source-dra	in diode	•			<u> </u>	
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 2.5 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.8	1	V
t <sub>rr</sub>	reverse recovery time	$I_S = 2.5 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s};$	-	13	-	ns
Q <sub>r</sub>	recovered charge	$V_{GS}$ = 10 V; $V_{DS}$ = 30 V; $T_j$ = 25 °C	_	7	_	nC

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### 60 V, N-channel Trench MOSFET

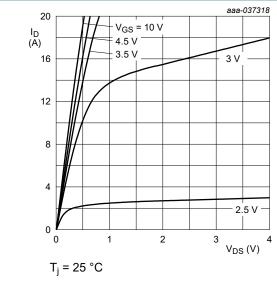


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

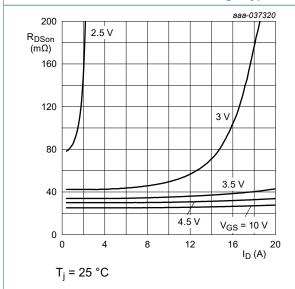


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

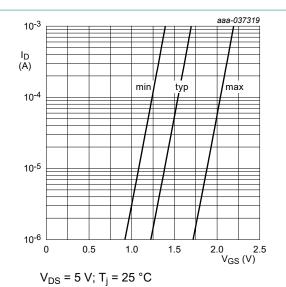


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

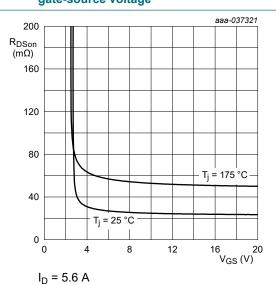


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

### **60 V, N-channel Trench MOSFET**

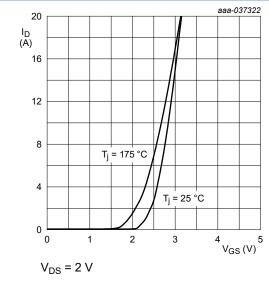


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

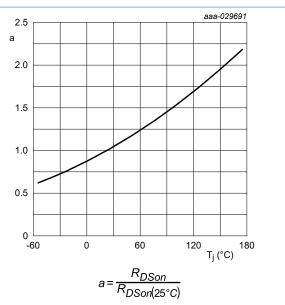


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

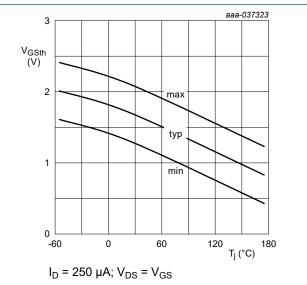
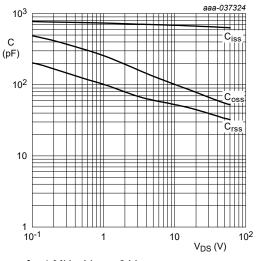


Fig. 12. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$ 

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

### 60 V, N-channel Trench MOSFET

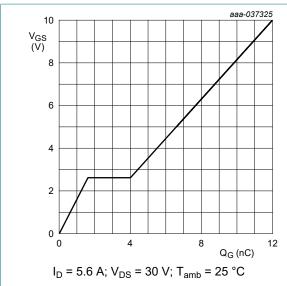


Fig. 14. Gate-source voltage as a function of gate charge; typical values

 $V_{GS} = 0 V$ 

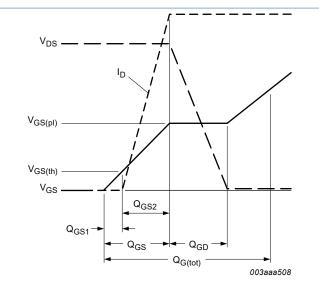


Fig. 15. Gate charge waveform definitions

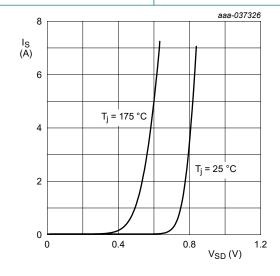
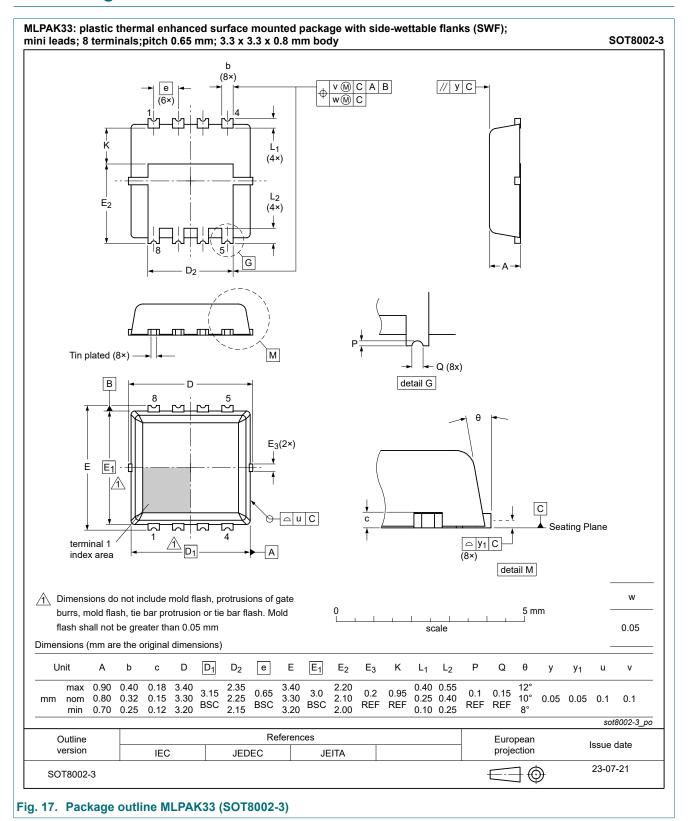


Fig. 16. Source current as a function of source-drain voltage; typical values

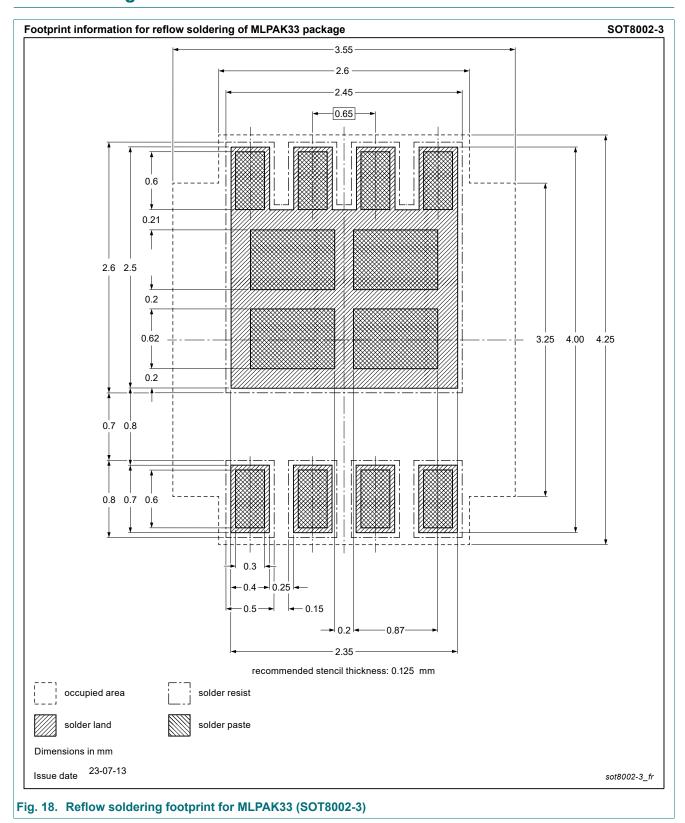
60 V, N-channel Trench MOSFET

# 11. Package outline



**60 V, N-channel Trench MOSFET** 

# 12. Soldering



#### 60 V, N-channel Trench MOSFET

## 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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